$\mathcal{N}_{\varepsilon \omega} \mathcal{Z}_{\varepsilon \text { rsey }} S_{\text {rmi-Conductor }} \mathcal{P}_{\text {roducts, }}$ Inc.

## NPN Silicon Epitaxial Planar Transistors

 designed for emitter-grounded AM and FM amplifier stages

Plastic case $\approx$ JEDEC TO-92
TO-18 compatible
The case is impervious to light
Weight approximately 0.18 g
Dimensions in mm

Absolute Maximum Ratings

|  | Symbol | Value | Unit |
| :---: | :---: | :---: | :---: |
| Collector Base Voltage | $V_{\text {ceo }}$ | 40 | V |
| Collector Emitter Voltage | $V_{\text {ceo }}$ | 40 | V |
| Emitter Base Voltage | $V_{\text {Ebo }}$ | 4 | V |
| Collector Current | $l_{c}$ | 25 | mA |
| Base Current | $\mathrm{I}_{\mathrm{B}}$ | 2 | mA |
| Power Dissipation at $\mathrm{T}_{\text {amb }}=25^{\circ} \mathrm{C}$ | $\mathrm{P}_{\text {tot }}$ | $300^{11}$ | mW |
| Junction Temperature | T | 150 | ${ }^{\circ} \mathrm{C}$ |
| Storage Temperature Range | $T_{s}$ | -55 $\ldots+150$ | ${ }^{\circ} \mathrm{C}$ |
| ${ }^{1)}$ Valid provided that leads are kept at ambient temperature at a distance of 2 mm from case |  |  |  |

N.J Semi-Conductors reserves the right to change test conditions, parameter limits and package dimensions without notice. Information furnished by NJ Semi-Conductors is believed to be both accurate and reliable at the time of going to press. However, NJ Semi-Conductors assumes no responsibility for any errors or omissions discovered in its use. NJ Semi-Conductors encourages customers to verify that datasheets are current before placing orders.

Quality Semi-Conductors

Characteristics at $\mathrm{T}_{\mathrm{amb}}=25^{\circ} \mathrm{C}$

|  | Symbol | Min. | Typ. | Max. | Value |
| :---: | :---: | :---: | :---: | :---: | :---: |
| DC Current Gain <br> at $V_{C E}=10 \mathrm{~V}, \mathrm{I}_{\mathrm{C}}=1 \mathrm{~mA}$ | $\begin{aligned} & h_{\mathrm{FE}} \\ & \mathrm{~h}_{\mathrm{FE}} \end{aligned}$ | $\begin{aligned} & 67 \\ & 36 \end{aligned}$ | - | $\begin{aligned} & 220 \\ & 125 \end{aligned}$ | - |
| Base Emitter Voltage at $\mathrm{V}_{C B}=10 \mathrm{~V}, \mathrm{I}_{\mathrm{C}}=1 \mathrm{~mA}$ | $V_{\text {bE }}$ | 650 | 700 | 740 | mV |
| Collector Cutoff Current at $\mathrm{V}_{C B}=20 \mathrm{~V}$ | $I_{\text {cbo }}$ | - | - | 100 | nA |
| Thermal Resistance Junction to Ambient | $\mathrm{R}_{\mathrm{thA}}$ | - | - | $420{ }^{11}$ | K/W |
| Collector Base Breakdown Voltage at $\mathrm{I}_{\mathrm{C}}=10 \mu \mathrm{~A}$ | $V_{\text {(вя) сяо }}$ | 40 | - | - | V |
| Collector Emitter Breakdown Voltage at $\mathrm{l}_{\mathrm{C}}=2 \mathrm{~mA}$ | $V_{\text {(ba)CEO }}$ | 40 | - | - | V |
| Emitter Base Breakdown Voltage at $t_{E}=10 \mu \mathrm{~A}$ | $V_{(B R) E B O}$ | 4 | - | - | V |
| Gain Bandwidth Product at $\begin{array}{ll}V_{C B}=10 \mathrm{~V}, \mathrm{I}_{\mathrm{C}}=1 \mathrm{~mA}, \mathrm{t}=100 \mathrm{MHz} & \\ & \text { BF240 } \\ & \text { BF241 }\end{array}$ | $\begin{aligned} & f_{T} \\ & f_{T} \end{aligned}$ | - | $\begin{aligned} & 430 \\ & 400 \end{aligned}$ | - | $\begin{aligned} & \mathrm{MHz} \\ & \mathrm{MHz} \end{aligned}$ |
| Feedback Capacitance at $\mathrm{V}_{\mathrm{CB}}=10 \mathrm{~V}, \mathrm{I}_{\mathrm{C}}=1 \mathrm{~mA}, \mathfrak{f}=1 \mathrm{MHz}$ | $-\mathrm{C}_{\text {re }}$ | - | 0.27 | - | pF |
| Noise Figure (emitter grounded) <br> at $V_{C B}=10 \mathrm{~V}, \mathrm{I}_{\mathrm{C}}=1 \mathrm{~mA}$ <br> $g_{s}=5 \mathrm{~ms}, 1=200 \mathrm{kHz}$ <br> $y_{s}=(6.6-j 3.3) \mathrm{mS}, \mathrm{f}=100 \mathrm{MHz}$ | $\begin{aligned} & F \\ & F \end{aligned}$ | - | $\begin{aligned} & 1.5 \\ & 1.6 \end{aligned}$ | 3.5 | $\begin{aligned} & \mathrm{dB} \\ & \mathrm{~dB} \end{aligned}$ |
| Output Admittance <br> at $\mathrm{V}_{\mathrm{CB}}=10 \mathrm{~V}, \mathrm{I}_{\mathrm{C}}=1 \mathrm{~mA}, \mathrm{f}=10.7 \mathrm{MHz}$ <br> at $\mathrm{V}_{\mathrm{CB}}=10 \mathrm{~V}, \mathrm{I}_{\mathrm{C}}=1 \mathrm{~mA}, f=470 \mathrm{kHz}$ | $\begin{aligned} & \mathrm{g}_{\circ e} \\ & \mathrm{~g}_{\text {oe }} \end{aligned}$ | - | - | $\begin{aligned} & 10.5 \\ & 8.3 \end{aligned}$ | ${ }_{\mu \mathrm{S}}^{\mu \mathrm{S}}$ |

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[^0]:    ${ }^{1 /}$ Valid provided that leads are kept at ambient temperature at a distance of 2 mm from case

